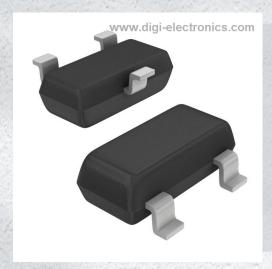


MMBTA92LT1 Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number MMBTA92LT1-DG

Manufacturer onsemi

Manufacturer Product Number MMBTA92LT1

Description TRANS PNP 300V 500MA SOT23

Detailed Description Bipolar (BJT) Transistor PNP 300 V 500 mA 50MHz 2

25 mW Surface Mount SOT-23-3 (TO-236)



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
MMBTA92LT1	onsemi
Series:	Product Status:
	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
PNP	500 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
300 V	500mV @ 2mA, 20mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
250nA	25 @ 1mA, 10V
Power - Max:	Frequency - Transition:
225 mW	50MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
TO-236-3, SC-59, SOT-23-3	SOT-23-3 (TO-236)
Base Product Number:	
MMBTA92	

Environmental & Export classification

8541.21.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
RoHS non-compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



High Voltage Transistors PNP Silicon MMRTA921 SMMRTA921

MMBTA92L, SMMBTA92L, MMBTA93L

Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	92	93	Unit
Collector - Emitter Voltage	V_{CEO}	-300	-200	Vdc
Collector - Base Voltage	V_{CBO}	-300	-200	Vdc
Emitter – Base Voltage	V _{EBO}	-5.0	-5.0	Vdc
Collector Current – Continuous	I _C	-500		mAdc

DEVICE MARKING

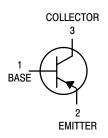
MMBTA92L, SMMBTA92L = 2D; MMBTA93LT1 = 2E

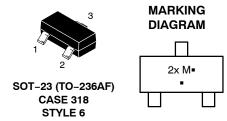
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) $T_A = 25^{\circ}C$	P_D	225	mW
Derate above 25°C		1.8	mW/°C
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation (Note 2) Alumina Substrate, (2) T _A = 25°C	P _D	300	mW
Derate above 25°C		2.4	mW/°C
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in.
- 2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.





2x = Specific Device Code M = Date Code*

= Pb–Free Package

(*Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MMBTA92LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
SMMBTA92LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
MMBTA92LT3G	SOT-23 (Pb-Free)	10000 / Tape & Reel
SMMBTA92LT3G	SOT-23 (Pb-Free)	10000 / Tape & Reel
MMBTA93LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MMBTA92L, SMMBTA92L, MMBTA93L

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (Note 3) $(I_C = -1.0 \text{ mAdc}, I_B = 0)$	MMBTA92, SMMBTA92 MMBTA93	V _{(BR)CEO}	-300 -200	- -	Vdc
Collector – Base Breakdown Voltage (I _C = –100 μAdc, I _E = 0)	MMBTA92, SMMBTA92 MMBTA93	V _{(BR)CBO}	-300 -200	- -	Vdc
Emitter – Base Breakdown Voltage ($I_E = -100 \mu Adc, I_C = 0$)		V _{(BR)EBO}	-5.0	-	Vdc
Collector Cutoff Current $(V_{CB} = -200 \text{ Vdc}, I_E = 0)$ $(V_{CB} = -160 \text{ Vdc}, I_E = 0)$	MMBTA92, SMMBTA92 MMBTA93	I _{CBO}	- -	-0.25 -0.25	μAdc
Emitter Cutoff Current (V _{EB} = -3.0 Vdc, I _C = 0)		I _{EBO}	-	-0.1	μAdc
ON CHARACTERISTICS (Note 3)				•	•
DC Current Gain $ (I_C = -1.0 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) $ $ (I_C = -10 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) $	Both Types Both Types	h _{FE}	25 40	- -	-
$(I_C = -30 \text{ mAdc}, V_{CE} = -10 \text{ Vdc})$	MMBTA92, SMMBTA92 MMBTA93		25 25	- -	
Collector – Emitter Saturation Voltage (I _C = -20 mAdc, I _B = -2.0 mAdc)	MMBTA92, SMMBTA92 MMBTA93	V _{CE(sat)}	- -	-0.5 -0.5	Vdc
Base-Emitter Saturation Voltage (I _C = -20 mAdc, I _B = -2.0 mAdc)		V _{BE(sat)}	_	-0.9	Vdc
SMALL-SIGNAL CHARACTERISTICS				-	-
Current – Gain — Bandwidth Product (I _C = –10 mAdc, V _{CE} = –20 Vdc, f = 100 MHz)		f _T	50	-	MHz
Collector-Base Capacitance (V _{CB} = -20 Vdc, I _E = 0, f = 1.0 MHz)	MMBTA92, SMMBTA92 MMBTA93	C _{cb}	- -	6.0 8.0	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

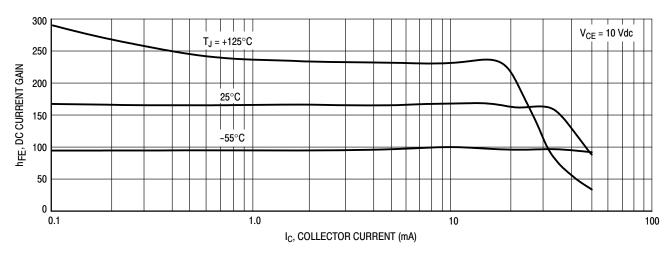
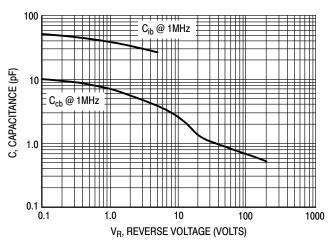


Figure 1. DC Current Gain

MMBTA92L, SMMBTA92L, MMBTA93L



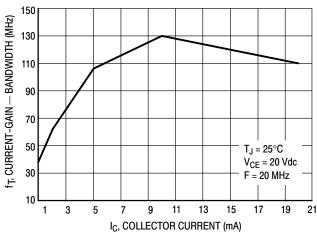
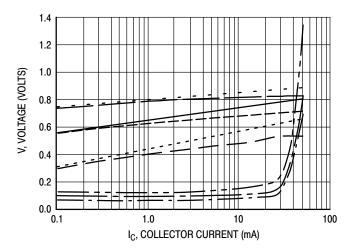


Figure 2. Capacitance

Figure 3. Current-Gain - Bandwidth



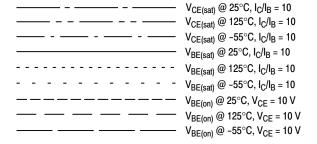


Figure 4. "ON" Voltages

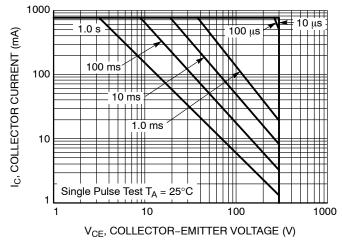


Figure 5. Safe Operating Area



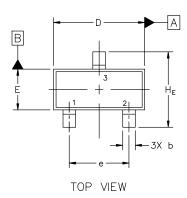
MECHANICAL CASE OUTLINE

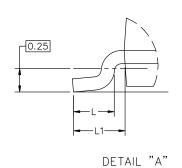
PACKAGE DIMENSIONS

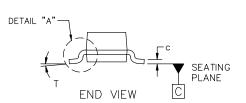


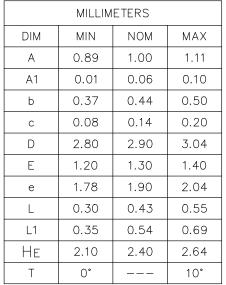
SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318 ISSUE AU**

DATE 14 AUG 2024









NOTES:

- DIMENSIONING AND TOLERANCING 1.
- PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS: MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE
- BASE MATERIAL.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

GENERIC MARKING DIAGRAM*

SIDE VIEW

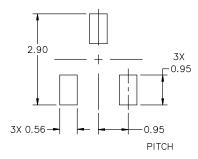


XXX = Specific Device Code

= Date Code

= Pb-Free Package

^{*}This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.



Scale 3:1

RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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DATE 14 AUG 2024

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: STYLE 8: PIN 1. EMITTER PIN 1. ANOD 2. BASE 2. NO CC 3. COLLECTOR 3. CATHO	ONNECTION	
STYLE 9: PIN 1. ANODE 2. ANODE 3. CATHODE	STYLE 10: PIN 1. DRAIN 2. SOURCE 3. GATE	STYLE 11: STYLE 12: PIN 1. ANODE PIN 1. CATHO 2. CATHODE 2. CATHO 3. CATHODE-ANODE 3. ANODO	ODE 2. DRAIN 2. GATE	
STYLE 15: PIN 1. GATE 2. CATHODE 3. ANODE	STYLE 16: PIN 1. ANODE 2. CATHODE 3. CATHODE	STYLE 17: STYLE 18: PIN 1. NO CONNECTION PIN 1. NO CO 2. ANODE 2. CATHO 3. CATHODE 3. ANODO	ODE 2. ANODE 2. ANODE	
STYLE 21: PIN 1. GATE 2. SOURCE 3. DRAIN	STYLE 22: PIN 1. RETURN 2. OUTPUT 3. INPUT	STYLE 23: STYLE 24: PIN 1. ANODE PIN 1. GATE 2. ANODE 2. DRAIN 3. CATHODE 3. SOURCE		CTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE			

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